



## DMTH10H015SPS

### 100V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> T <sub>C</sub> = +25°C
1001/	14.5mΩ @ V <sub>GS</sub> = 10V	50.5A
100V	19.5mΩ @ V <sub>GS</sub> = 6V	43.6A

### Description

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize R<sub>DS(ON)</sub>, yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switch.

# Applications

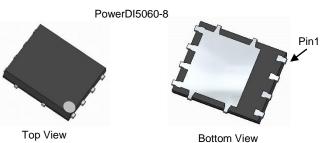
- Motor Control
- **DC-DC Converters**
- **Power Management**

### Features

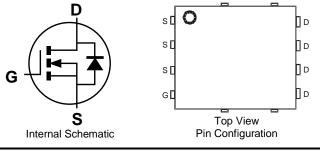
- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production-Ensures More Reliable and Robust End Application
- Thermally Efficient Package—Cooler Running Applications
- Low RDS(ON)-Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.097 grams (Approximate)







# Ordering Information (Note 4)

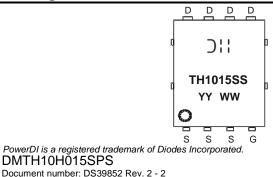
Part Number	Case	Packaging
DMTH10H015SPS-13	PowerDI5060-8	2500/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, see https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



D¦¦ = Manufacturer's Marking TH1015SS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



# **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	100	V		
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
	Steady State	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	I <sub>D</sub>	8.4 5.9	А
Continuous Drain Current (Note 5) $V_{GS} = 10V$	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ID	50.5 35.7	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	120	A	
Maximum Continuous Body Diode Forward Current (No	Is	1.5	A		
Avalanche Current (Note 7) L = 3mH	I <sub>AS</sub>	7.5	А		
Avalanche Energy (Note 7) L = 3mH			Eas	85	mJ
Avalanche Current, L = 0.1mH			I <sub>AS</sub>	15.8	А
Avalanche Energy, L = 0.1mH			E <sub>AS</sub>	12.5	mJ

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)		R <sub>ÐJA</sub>	98	°C/W
Total Power Dissipation	T <sub>C</sub> = +25°C	PD	55	W
Thermal Resistance, Junction to Case	R <sub>eJC</sub>	2.7	°C/W	
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

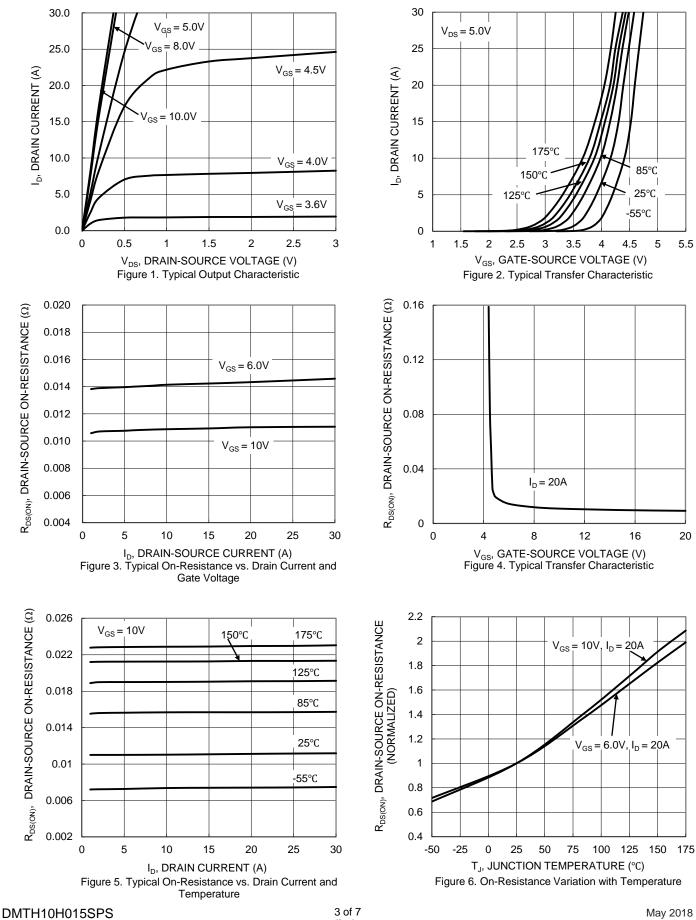
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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)			-				
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	—		V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	_	1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	—	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	2	—	4	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		—	11.3	14.5	mΩ	$V_{GS} = 10V, I_D = 20A$	
	R <sub>DS(ON)</sub>	—	14.7	19.5	11152	$V_{GS} = 6V, I_D = 20A$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.9	1.3	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	2343	_		$V_{DS} = 50V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	C <sub>oss</sub>	_	487	_	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	26	_			
Gate Resistance	R <sub>G</sub>	_	0.69	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Q <sub>G</sub>	_	30.1	_			
Gate-Source Charge	Q <sub>GS</sub>	_	7.5	_	nC	$V_{DD} = 50V, I_D = 10A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q <sub>GD</sub>	_	6.5	_		$v_{GS} = 10v$	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	9.8	_		$V_{DD} = 50V, V_{GS} = 10V,$ $I_D = 10A, R_G = 6\Omega$	
Turn-On Rise Time	t <sub>R</sub>	_	7.8	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	22.5		ns		
Turn-Off Fall Time	t <sub>F</sub>	_	9.6		]		
Reverse Recovery Time	t <sub>RR</sub>	_	43.1		ns		
Reverse Recovery Charge	Q <sub>RR</sub>		65.1		nC	- I <sub>F</sub> = 10A, di/dt = 100A/μs	

 Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.
Short duration pulse test used to minimize self-heating effect. Notes:

7. Guaranteed by design. Not subject to product testing.



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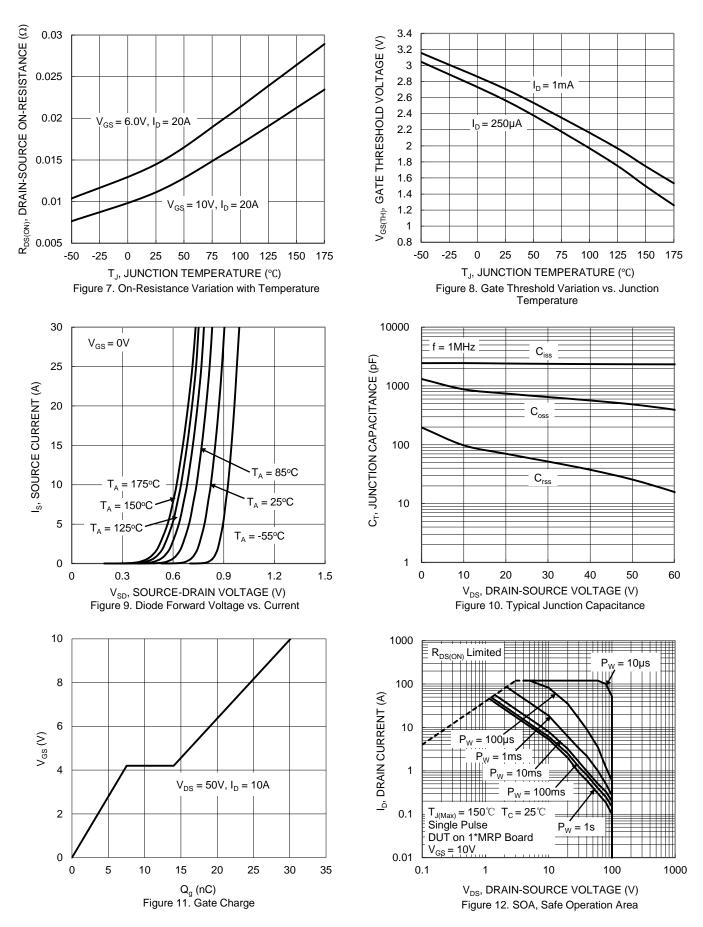


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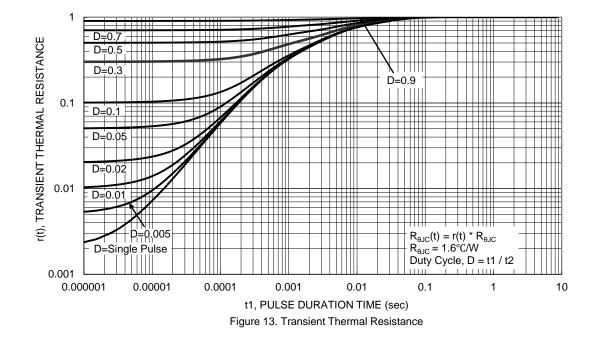




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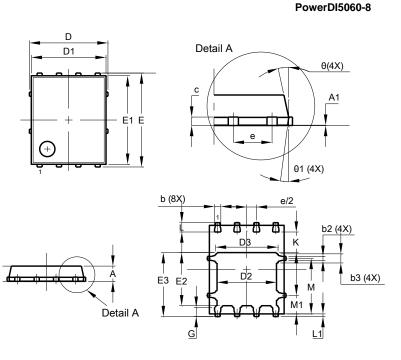






# **Package Outline Dimensions**

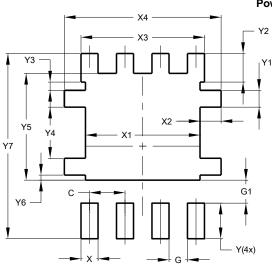
Please see http://www.diodes.com/package-outlines.html for the latest version.



	PowerDI5060-8					
Dim	Min	Тур				
Α	0.90	0.90 1.10				
A1	0.00	0.05	_			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC	;			
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90 4.30		4.10			
E	(	6.15 BSC				
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	99 4.39 4.1				
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
AI	Dimens	ions in m	າຫ			

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8

Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
X3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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